PCN10331 - Introducing a new Assembly and Test location for products assembled in SOT23 5L package

WHAT is the change?

Progressing on activities related to process modernization and quality improvement, ST is pleased to announce the introduction of TSHT/China as an added subcontractor for Assy and Test & Finishing activities for some products assembled in our SOT23 5L package.

The list of test vehicles used for the validation is listed here below.

Commercial Product	Current Finished Good	Current Assy & TnF Plant	Added Finished Good	Added Assy & TnF Plant
LD2981CM33TR	LD2981CM33TR\$2V	Carsem	LD2981CM33TR\$1R	TSHT
LDK120M-R	LDK120M-R\$3V	Carsem	LDK120M-R\$1R	TSHT

Dedicated engineering trials and test vehicles have been defined to validate the change.

WHY:

The purpose of the introduction of TSHT for both Assy and Test & Finishing activities for the here above listed commercial products is to further improve the rationalization of our manufacturing assets and provide a better support to our customers by enhancing the manufacturing process for higher volume production.

WHEN will this change occur?

The following table lists all relevant information

Commercial Product	Added F.G.	Added F.G. Test Vehicles Samples Availability		Estimated First Shipment Date	
LD2981CM33TR	LD2981CM33TR\$1R	Upon request	Wk26′17	Sep. '17	
LDK120M-R	LDK120M-R\$1R	Upon request	Wk26'17	Sep. '17	

HOW will the change be qualified?

• The qualification is based on Test vehicle representatives by using internal ST rule for changes.

IMPACTS OF THE CHANGE:

Form: No change
Fit: No change

Function: No change

Attached files: Reliability validation report



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REL. 6088-192-W-2017

Reliability Report

New Subcontractor

SOT23 in SC-Tianshui Huatian-China (TSHT)

TVs: LDK120 (UI69) & LD2981(KR33)

General Information

Product Lines

200 mA low quiescent **Product Description** current very low noise LDO

P/N LDK120M-R\$4V

Product Group AMG (Analog & MEMS Group)

General Purpose Analog & RF

Product division Division

POWER MANAGEMENT SOT23 5L - 1.0mil Pd-Cu **Package**

Silicon Process technology BCD6S Locations

Wafer fab CTM8

SC-Tianshui Huatian-China Assembly plant

(TSHT)

Reliability Lab Catania Reliability LAB

General Information

Product Lines

Very Low Drop VREG @ **Product Description**

100mA 3.3 V

P/N LD2981ABM33TR\$3V

Product Group AMG (Analog & MEMS Group) General Purpose Analog & RF

Product division Division

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Package SOT23 5L - 1.0mil Pd-Cu

Silicon Process technology BI20II Locations

Wafer fab Singapore 6

SC-Tianshui Huatian-China Assembly plant

(TSHT)

Reliability Lab Catania Reliability LAB

DOCUMENT INFORMATION

Version	Date	Pages	Prepared by	Approved by	Comment
1.0	.lun-2017	7	Giuseppe Failla	Giovanni Presti	Final Report

Note: This report is a summary of the reliability trials performed in good faith by STMicroelectronics in order to evaluate the potential reliability risks during the product life using a set of defined test methods.

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1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference	Short description		
JESD47	Stress-Test-Driven Qualification of Integrated Circuits		

2 GLOSSARY

DUT	Device Under Test
SS	Sample Size
PCB	Printed Circuit Board

3 RELIABILITY EVALUATION OVERVIEW

3.1 Objectives

To qualify the SOT23 in the subcontractor SC-Tianshui Huatian-China (TSHT)

In order to cover the FE/BE compatibility two TVs in different technologies have been chosen:

- TV1: LDK120M-R\$4V (UI69) diffused in BCD6S
- TV2: LD2981ABM33TR\$3V (KR33) diffused in BI20II.

BE Process

To be qualified

3 different Lots + 2 different BE CLs for each Test Vehicle are requested

3.2 Conclusion

Qualification Plan requirements have been fulfilled without exception. It is stressed that reliability tests have shown that the devices behave correctly against environmental tests (no failure). Moreover, the stability of electrical parameters during the accelerated tests demonstrates the ruggedness of the products and safe operation, which is consequently expected during their lifetime.

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4 DEVICE CHARACTERISTICS

4.1 Device description

 The LDK120 low drop voltage regulator provides 200 mA of maximum current from an input supply voltage in the range of 1.9 V to 5.5 V, with a typical dropout voltage of 100 mV. It is stabilized with a ceramic capacitor on the output.

The very low drop voltage, low quiescent current and low noise features make it suitable for low power battery-powered applications. An enable logic control function puts the LDK120 in shutdown mode allowing a total current consumption lower than 1 μ A. The device also includes a short-circuit constant current limiting and thermal protection.

• The LD2981 is a 100 mA fixed-output voltage regulator. The low-drop voltage and the ultra low quiescent current make them suitable for low noise, low power applications and in battery powered systems. The quiescent current in sleep mode is less than 1 μA when INHIBIT pin is pulled low. Shutdown logic control function is available on pin n° 3 (TTL compatible). This means that when the device is used as local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. The LD2981 is designed to work with low ESR ceramic capacitor. Typical applications are in cellular phone, palmtop/laptop computer, personal digital assistant (PDA), personal stereo, camcorder and camera.

4.2 Construction note

	LDK120M-R\$4V (UI69)	LD2981ABM33TR\$3V (KR33)			
Wafer/Die fab. information	· · · · · · · · · · · · · · · · · · ·				
Wafer fab manufacturing location	CT8	AMK6			
Technology	BCD6S	BI20II			
Die finishing back side	RAW SILICON	LAPPED SILICON			
Die size	782 x 736 um	1470 x 990 um			
Bond pad metallization layers	Ti/AlCu/TiNARC	AlSi			
Passivation type	TEOS/SiN/Polyimide	P-Vapox/Nitride/Polyimide(PIQ)			
Assembly information					
Assembly site	SC-Tianshui Huatian-China (TSHT)				
Package description	SOT 2	3 5L			
Molding compound	Epo	ху			
Frame	SOT235 A194 ((52X72) -16P			
Die attach process	GLUE				
Wires bonding materials/diameters	1.0mil Pd Cu				
Lead finishing process	Pure Tin Platir	ng Sn 100%			



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5 TESTS RESULTS SUMMARY

5.1 Test plan and results summary

TV1: LDK120M-R\$4V (UI69)

Test	РС	Std ref.	Conditions	Sto	ne			SS		
rest	٦٢٥	Sta rei.	Conditions	Sie	Steps		Lot 2	Lot 3	Lot 1-CL	Lot 1-CL
Die Oriented Tests (*)									LL	HH
Die Offenten Tests ()								parameter	parameter	
		JESD22		168		0/77				
HTOL		A-108	Tj = 125°C, V= Vbias +7V	500		0/77				
		71.00		1000) H	0/77				
		JESD22		168	Н	0/25	0/25	0/25	0/25	0/25
HTSL		A-103	Ta = 150°C	500	I	0/25	0/25	0/25	0/25	0/25
		A-103		1000) H	0/25	0/25	0/25	0/25	0/25
Packag	ge Oı	riented Tests	s (*)							
PC		JESD22 A-113	Drying 24 H @ 125°C Store 168 H @ Ta=85°C Rh=85% Oven Reflow @ Tpeak=260°C 3 times	Fina	al	pass	pass	pass	pass	pass
AC	Υ	JESD22 A-102	Pa=2Atm / Ta=121°C	96	h	0/25	0/25	0/25		
		IEOD00		100	су	0/25	0/25	0/25	0/25	0/25
TC	Υ	JESD22 A-104	Ta = -65°C to 150°C	200	су	0/25	0/25	0/25	0/25	0/25
		A-104		500	су	0/25	0/25	0/25	0/25	0/25
		150500		168	H	0/25	0/25	0/25		
THB	Υ	JESD22	Ta = 85°C, RH = 85%, Bias +5,5V	500	Н	0/25	0/25	0/25		
		A-101		1000) H	0/25	0/25	0/25		
Other Tests										
ESD		JESD22-C101	CDM	500 750 corn pin	V ier	Pass				
CA			Construction Analysis			Pass				

Note (*) All samples have been assembled on dedicated PCB in agreement with JEDEC020 spec.



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TV2: LD2981ABM33TR\$3V (KR33)

Test	РС	Std ref. Conditions Steps		Steps			SS			
1631	. 0	Old Tell	Conditions		Oteps	Lot 4	Lot 5	Lot 6	Lot 4-CL	Lot 4-CL
Die Ori	Die Oriented Tests								LL	HH
DIC OII	CIIIC	u 10313							parameter	parameter
		JESD22			168 H	0/77				
HTOL		A-108	Tj = 125°C, V= Vbias +20V		500 H	0/77				
		71 100			1000 H	0/77				
		JESD22			168 H	0/25	0/25	0/25	0/25	0/25
HTSL		A-103	Ta = 150°C		500 H	0/25	0/25	0/25	0/25	0/25
		A-103			1000 H	0/25	0/25	0/25	0/25	0/25
Packag	je Oi	riented Tests	3							
PC		JESD22 A-113	Drying 24 H @ 125°C Store 168 H @ Ta=85°C Rh=85% Oven Reflow @ Tpeak=260°C 3 times		Final	pass	pass	pass	pass	pass
AC	Υ	JESD22 A-102	Pa=2Atm / Ta=121°C		96 h	0/25	0/25	0/25		
		IEOD00			100cy	0/25	0/25	0/25	0/25	0/25
TC	Υ	JESD22	Ta = -65° C to 150° C		200cy	0/25	0/25	0/25	0/25	0/25
		A-104		500 cy	0/25	0/25	0/25	0/25	0/25	
					168 H	0/25	0/25	0/25		
THB	Υ	JESD22	Ta = 85°C, RH = 85%, Bias +16V		500 H	0/25	0/25	0/25		
		A-101	, ,		1000 H	0/25	0/25	0/25		
Other T	Other Tests									
ESD		JESD22-C101	CDM		500V 750V corner pins	pass				

Note:

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5.2 Tests Description

Test name	Description	Purpose				
Die Oriented						
HTOL High Temperature Operating Life	The device is stressed in static or dynamic configuration, approaching the operative max. absolute ratings in terms of junction temperature and bias condition.	simulates the devices operating condition in an				
HTSL High Temperature Storage Life	The device is stored in unbiased condition at the max. temperature allowed by the package materials, sometimes higher than the max. operative temperature.					
Package Oriented						
PC Preconditioning	The device is submitted to a typical temperature profile used for surface mounting devices	As preconditioning before other reliability tests: to verify that the surface mounting stress does not impact on the subsequent reliability performance.				
AC Auto Clave (Pressure Pot)	The device is stored in steam, at fixed and controlled conditions of humidity and temperature	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity				
TC Temperature Cycling	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal displacement, dielectric cracking, molding compound delamination, wire-bonds failure, die-attach layer degradation.				
THB Temperature Humidity Bias	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To evaluate the package moisture resistance				
Other						
ESD Electro Static Discharge	The device is submitted to a high voltage peak on all his pins simulating ESD stress according to different simulation models. CDM : Charged Device Model	To classify the device according to his susceptibility to damage or degradation by exposure to electrostatic discharge.				



Public Products List

Publict Products are off the shelf products. They are not dedicated to specific customers, they are available through ST Sales team, or Distributors, and visible on ST.com

PCN Title: Introduction of a new Assembly and Test & Finishing location for products assembled in SOT23 5L package

PCN Reference: AMG/17/10331

Subject: Public Products List

Dear Customer,

Please find below the Standard Public Products List impacted by the change.

LDK130M08R	LD2981ABM50TR	LD2980ABM33TR
LDK130M29R	LDK120M28R	LDK130M10R
LD2981ABM33TR	LDK120M18R	LDK130M25R
LDK120M08R	LDK120M12R	LDK130M12R
LDK120M15R	LDK130M32R	LDK130M15R
LDK120M10R	LDK120M32R	LD2980CM50TR
LDK120M30R	LDK120M29R	LD2980ABM50TR
LDK130M18R	LD2980ABM30TR	LDK120M11R
LDK120M31R	LDK120M25R	LD2980CM33TR
LD2981CM50TR	LDK120M33R	LD2980CM18TR
LDK130M33R		

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